STL128DN

High voltage fast-switching NPN power transistor

Features

- High voltage capability
- Low spread of dynamic parameters
- Very high switching speed
- Large RBSOA
- Integrated antiparallel collector-emitter diode

Applications

- Electronic ballast for fluorescent lighting
- Flyback and forward single transistor low power converters

Description

The device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and medium voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA. The device is designed for use in lighting applications and low cost switch-mode power supplies.

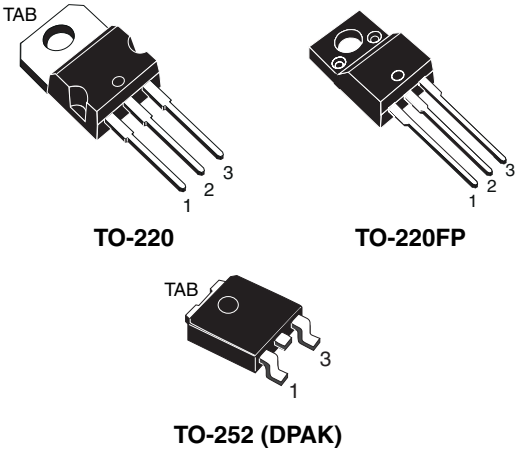


Figure 1. Internal schematic diagram

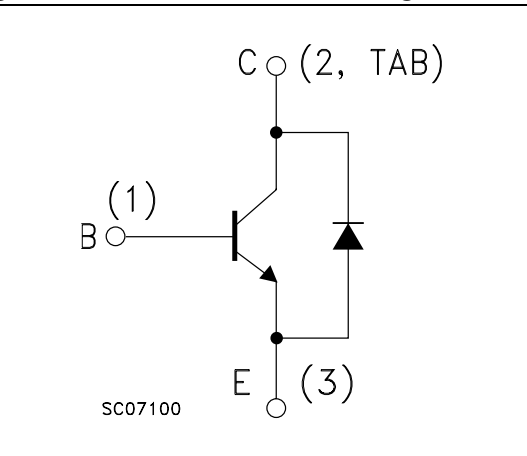


Table 1. Device summary

Order codes	Marking	Packages	Packaging
STL128DN	L128DN	TO-220	Tube
STL128DNFP	L128DNFP	TO-220FP	Tube
STLD128DNT4	LD128DN	DPAK	Tape and reel

Content

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter voltage (V_{BE} = 0)	700	V
V_{CEO}	Collector-emitter voltage (I_B = 0)	400	V
V_{EBO}	Base-emitter voltage (I_C = 0, I_B = 2 A, t_P < 10 µs)	$V_{(BR)EBO}$	V
I_C	Collector current	4	A
I_{CM}	Collector peak current (t_P < 5 ms)	8	A
I_B	Base current	2	A
I_{BM}	Base peak current (t_P < 5 ms)	4	A
P_{TOT}	Total dissipation at T_c = 25 °C for TO-220	60	W
	Total dissipation at T_c = 25 °C for TO-220FP	28	W
	Total dissipation at T_c = 25 °C for DPAK	20	W
T_{stg}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	TO-220	TO-220FP	DPAK	Unit
R_{thJC}	Thermal resistance junction-case max	2.08	4.46	6.25	°C/W

2 Electrical characteristics

T_{case} = 25 °C unless otherwise specified

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector cut-off current (V_{BE} = 0)	V_{CE} = 700 V V_{CE} = 700 V T_c = 125 °C			100 500	µA µA
I_{CEO}	Collector cut-off current (I_B = 0)	V_{CE} = 400 V			250	µA
$V_{(BR)EBO}$	Emitter-base breakdown voltage (I_C = 0)	I_E = 10 mA	9		18	V
$V_{CEO(sus)}$(1)	Collector-emitter sustaining voltage (I_B = 0)	I_C = 10 mA	400			V
$V_{CE(sat)}$(1)	Collector-emitter saturation voltage	I_C = 1 A I_B = 0.2 A I_C = 2 A I_B = 0.4 A			0.5 1	V V
$V_{BE(sat)}$(1)	Base-emitter saturation voltage	I_C = 1 A I_B = 0.2 A I_C = 2 A I_B = 0.4 A			1.2 1.3	V V
h_{FE}(1)	DC current gain	I_C = 10 mA V_{CE} = 5 V I_C = 2 A V_{CE} = 5 V	10 8		 24	
V_F	Diode forward voltage	I_F = 1 A			2.5	V
 t_s t_f	Resistive load Storage time Fall time	 I_C = 1 A I_{B1} = - I_{B2} = 0.2 A V_{CC} = 125 V t_p = 20 µs			 4.5 0.4	 µs µs

1. Pulse test: pulse duration ≤ 300 µs, duty cycle ≤ 2 %.

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area for TO-220

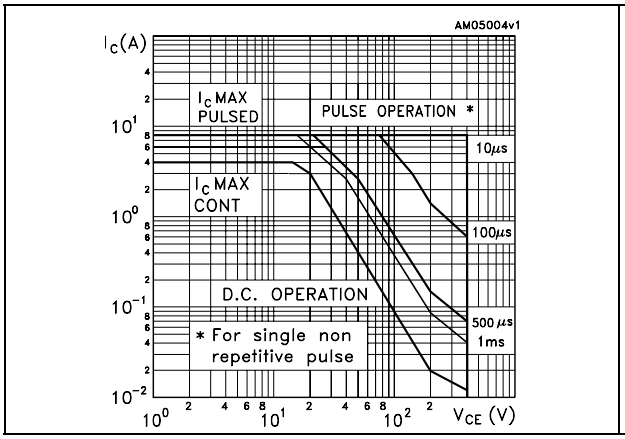


Figure 3. Safe operating area for TO-220FP

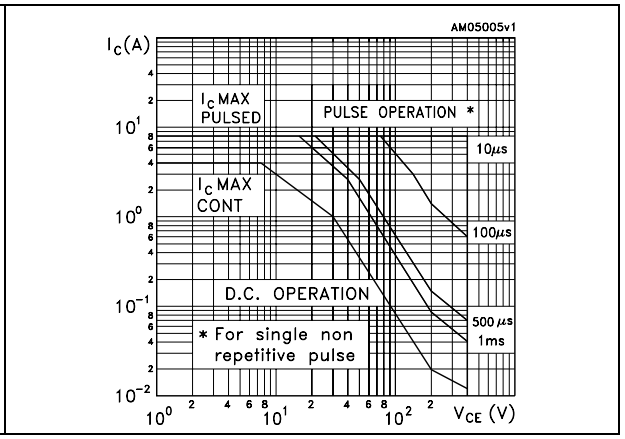


Figure 4. Safe operating area for DPAK

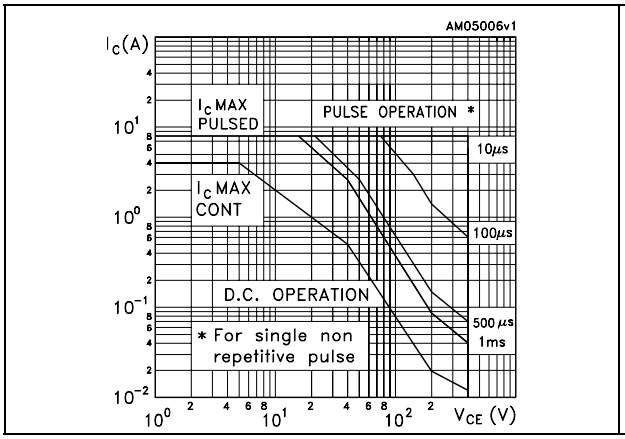


Figure 5. Derating curve

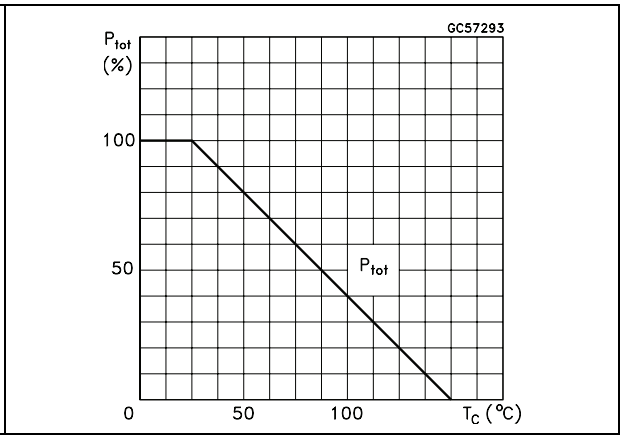


Figure 6. DC current gain (V_{CE} = 1 V)

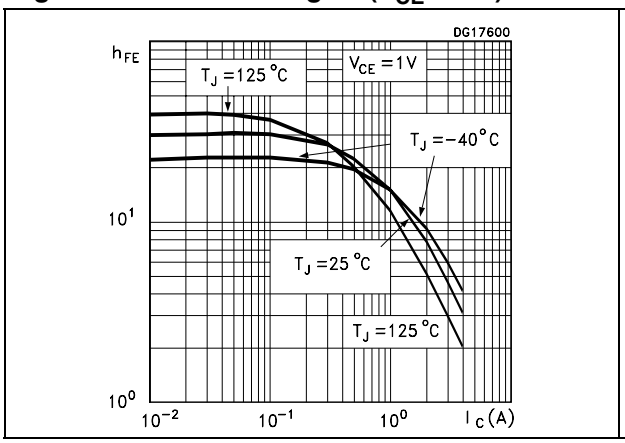


Figure 7. DC current gain (V_{CE} = 5 V)

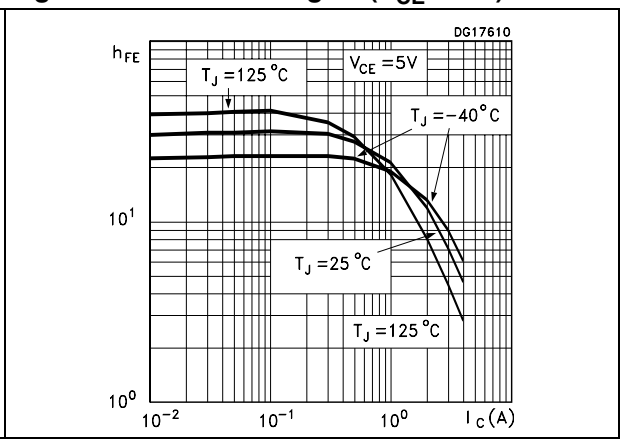


Figure 8. Collector-emitter saturation voltage

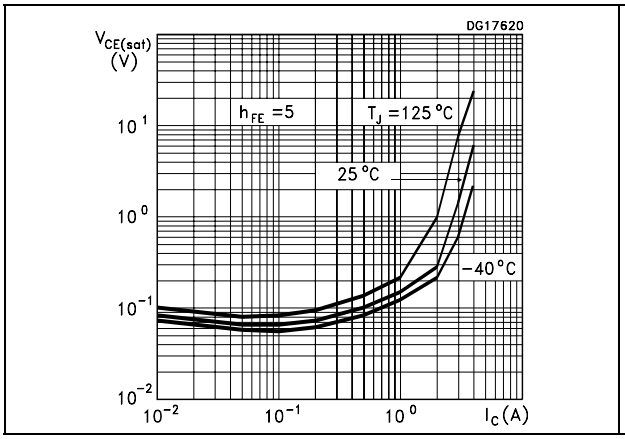


Figure 9. Base-emitter saturation voltage

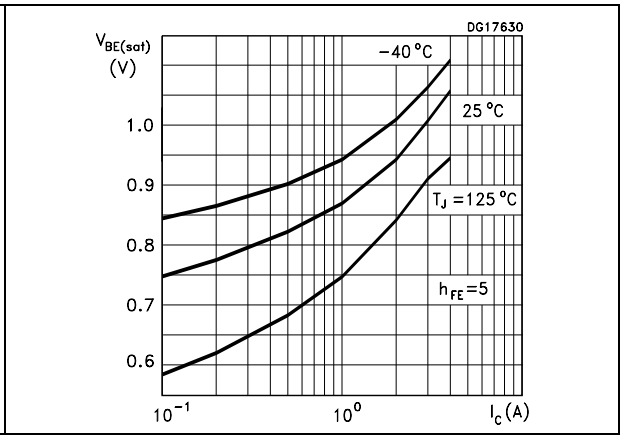


Figure 10. Freewheel diode forward voltage

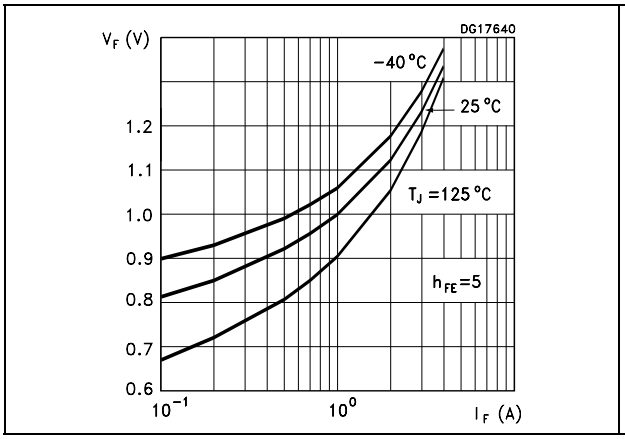


Figure 11. Resistive load switching time

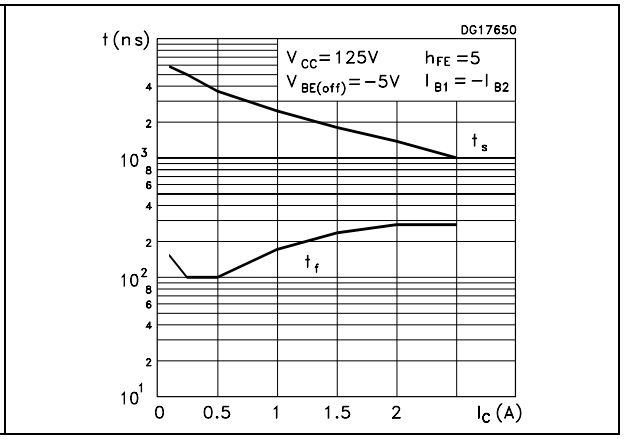
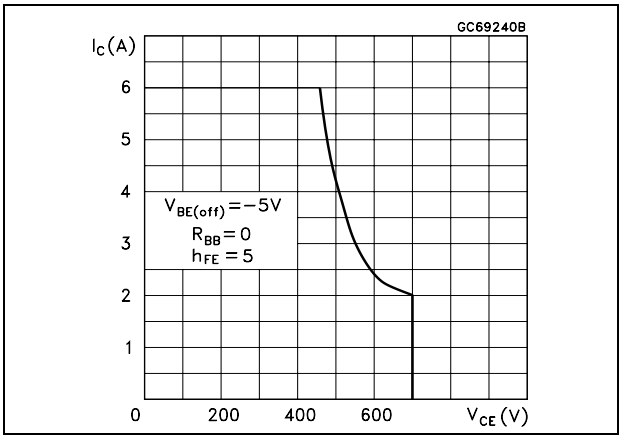
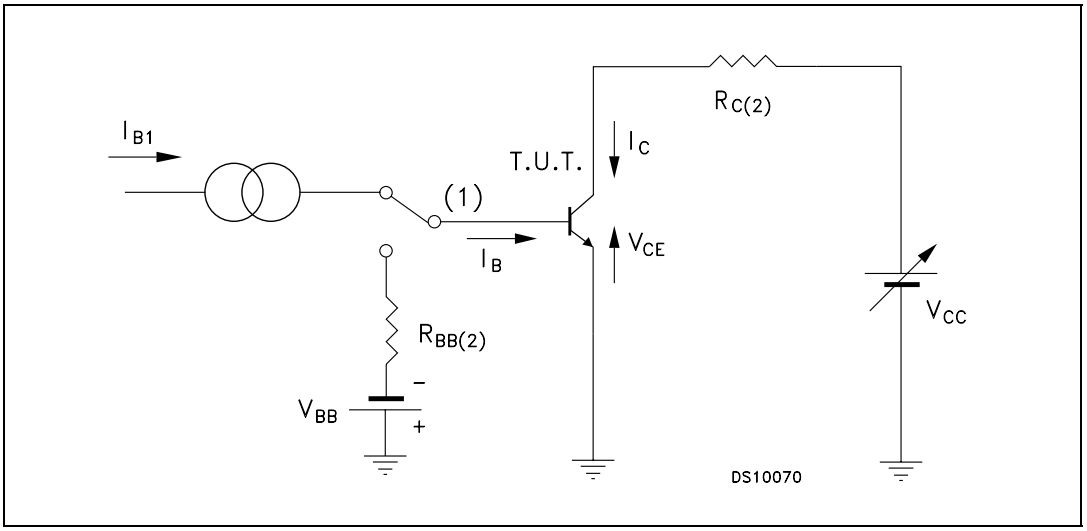


Figure 12. Reverse biased safe operating area



3 Test circuit

Figure 13. Resistive load switching test circuit



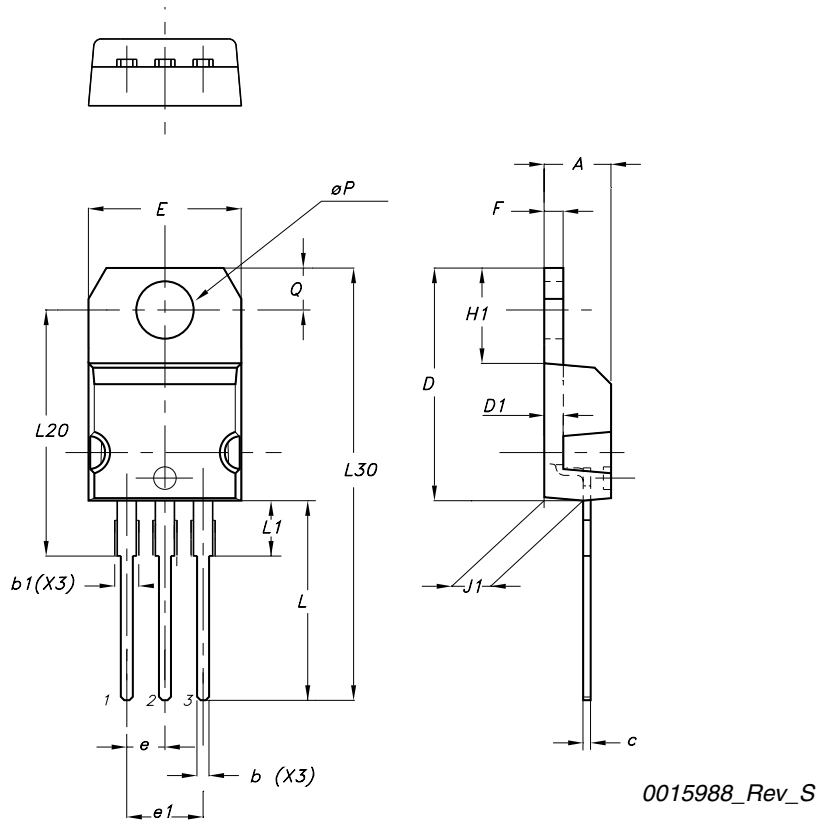
1. Fast electronic switch
2. Non-inductive resistor

4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: *www.st.com*.
ECOPACK® is an ST trademark.

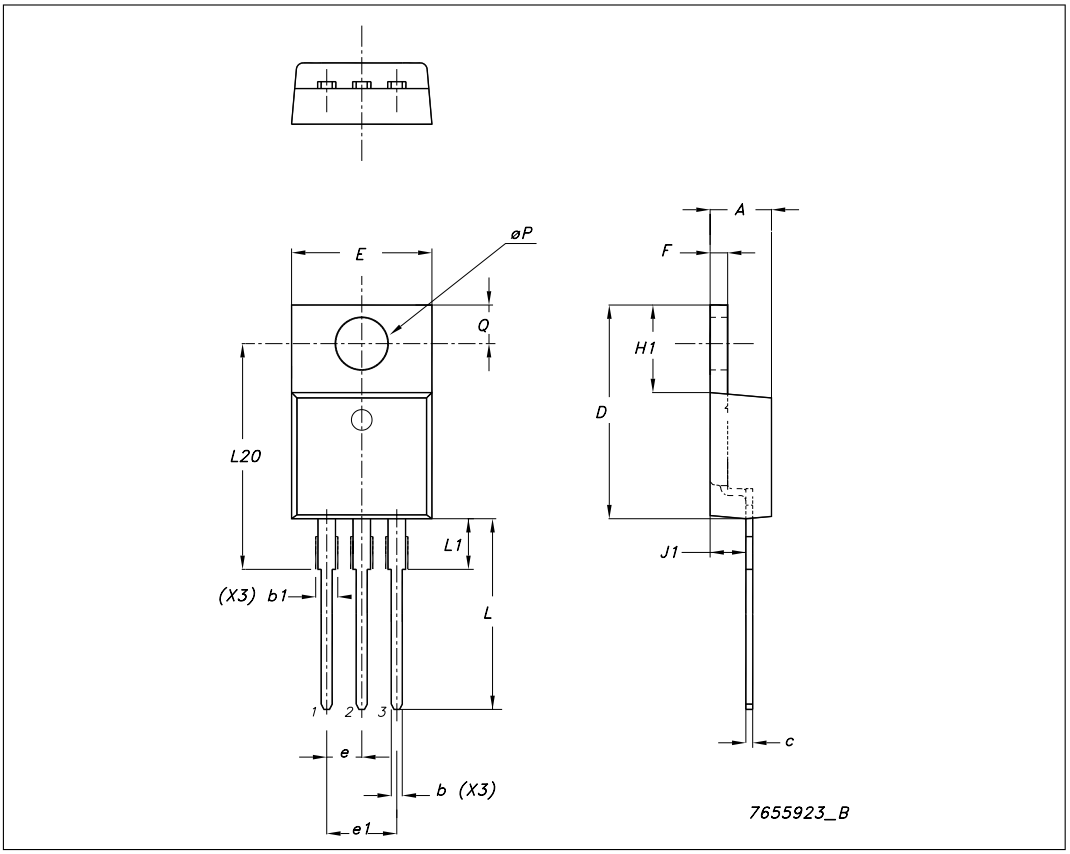
TO-220 type A mechanical data

Dim	mm		
	Min	Typ	Max
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
c	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
e	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
∅P	3.75		3.85
Q	2.65		2.95



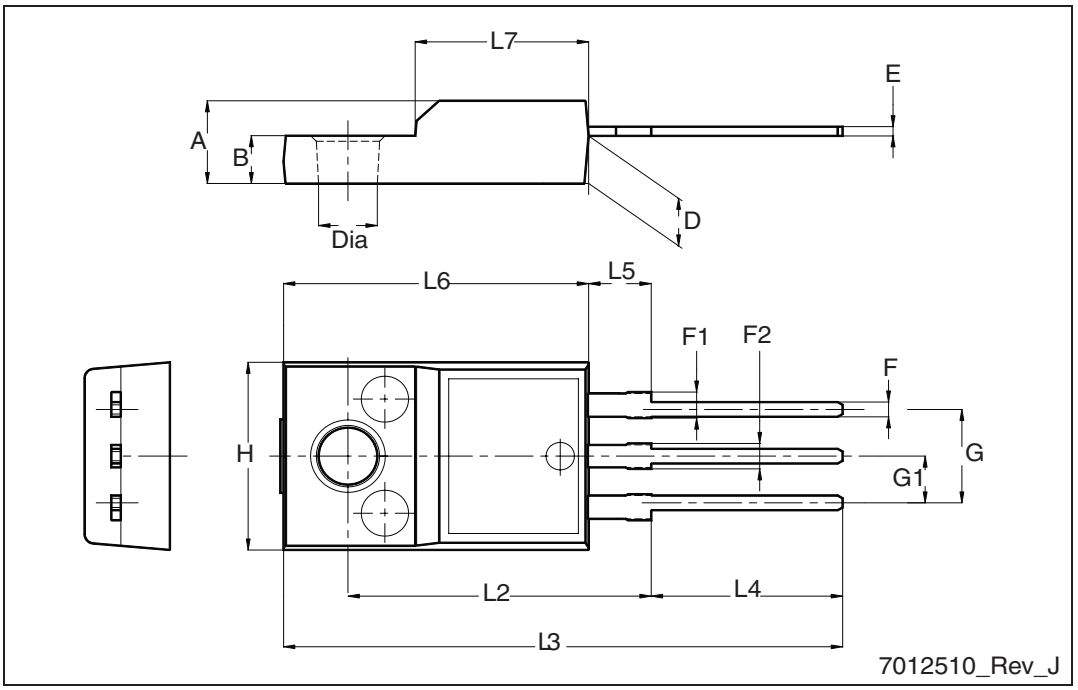
TO-220 type E mechanical data

Dim	mm		
	Min	Typ	Max
A	4.47		4.67
b	0.70		0.91
b1	1.17		1.37
c	0.31		0.53
D	14.60		15.70
E	9.96		10.36
e		2.54	
e1	4.98	5.08	5.18
F	1.17		1.37
H1	6.10		6.80
J1	2.52		2.82
L	12.70		13.80
L1	3.20		3.96
L20	15.21		16.77
øP	3.73		3.94
Q	2.59		2.89



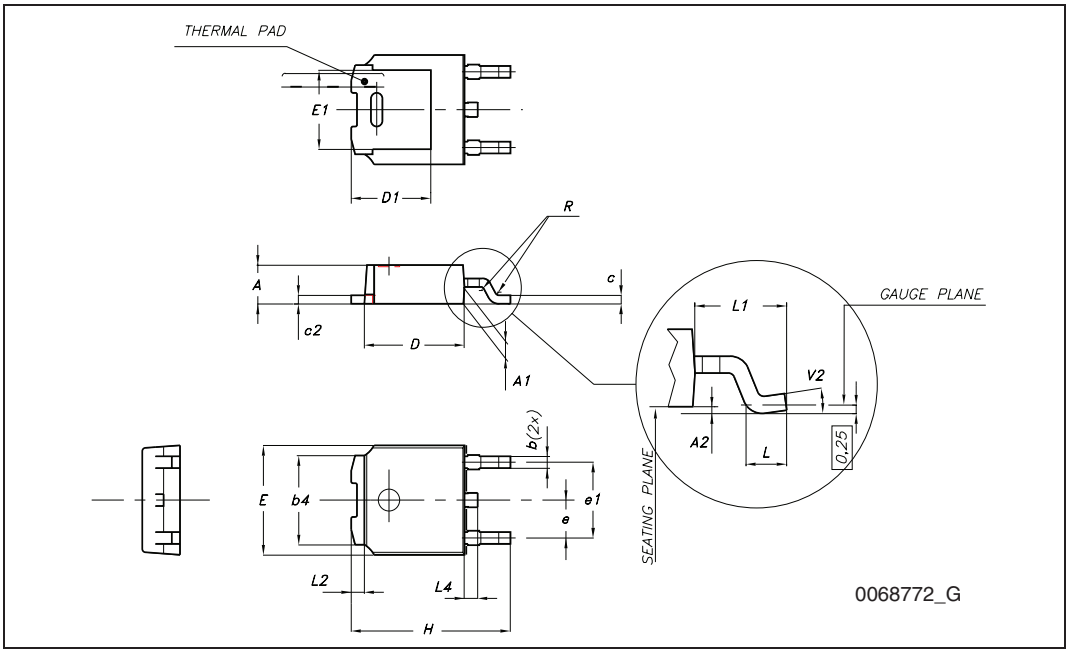
TO-220FP mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.4		4.6
B	2.5		2.7
D	2.5		2.75
E	0.45		0.7
F	0.75		1
F1	1.15		1.70
F2	1.15		1.5
G	4.95		5.2
G1	2.4		2.7
H	10		10.4
L2		16	
L3	28.6		30.6
L4	9.8		10.6
L5	2.9		3.6
L6	15.9		16.4
L7	9		9.3
Dia	3		3.2



TO-252 (DPAK) mechanical data

DIM.	mm.		
	min.	typ	max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
c	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
e		2.28	
e1	4.40		4.60
H	9.35		10.10
L	1		
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0 °		8 °



5 Revision history

Table 5. Document revision history

Date	Revision	Changes
04-Oct-2007	1	First release
14-Feb-2008	2	Updated TO-220, type E, mechanical data
01-Oct-2009	3	Updated: collector and base current values *Table 2 on page 3*, $V_{CE(sat)}$ maximum values *Table 4 on page 4*.

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